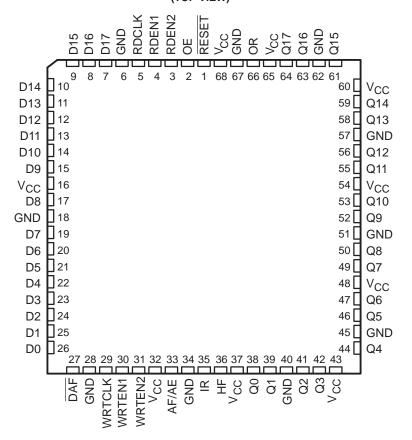
CLOCKED FIRST-IN, FIRST-OUT MEMORY

SCAS227E - FEBRUARY 1993 - REVISED APRIL 1998

- Member of the Texas Instruments Widebus™ Family
- Independent Asynchronous Inputs and Outputs
- Read and Write Operations Can Be Synchronized to Independent System Clocks
- Programmable Almost-Full/Almost-Empty Flag
- Pin-to-Pin Compatible With SN74ACT7882, SN74ACT7884, and SN74ACT7811

- Input-Ready, Output-Ready, and Half-Full Flags
- Expandable in Word Width and/or Word Depth
- Fast Access Times of 11 ns With a 50-pF Load
- High Output Drive for Direct Bus Interface
- Package Options Include 68-Pin Plastic Leaded Chip Carrrier (FN) or 80-Pin Shrink Quad Flat (PN) Package

FN PACKAGE (TOP VIEW)

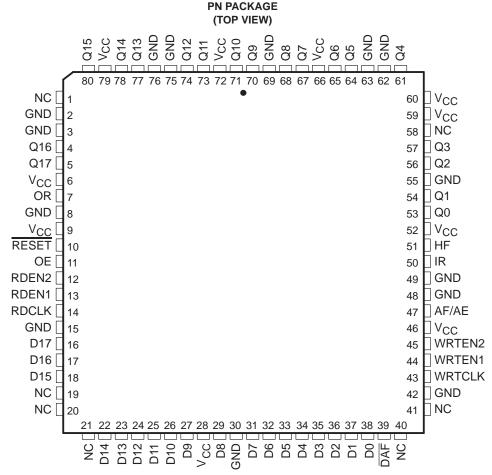




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Widebus is a trademark of Texas Instruments Incorporated.





NC - No internal connection

description

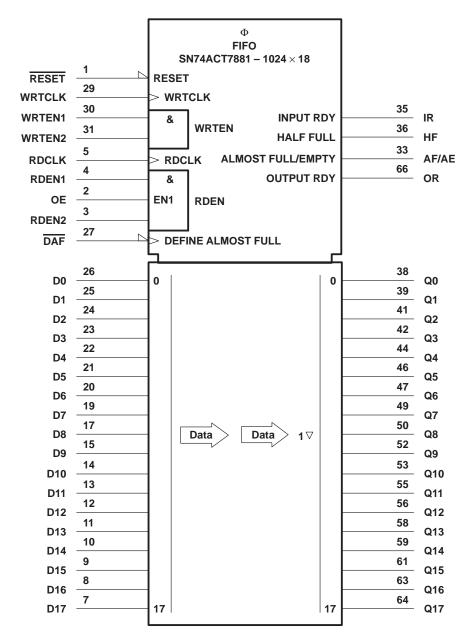
A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The SN74ACT7881 is organized as 1024×18 bits. The SN74ACT7881 processes data at rates up to 67 MHz and access times of 11 ns in a bit-parallel format. Data outputs are noninverting with respect to the data inputs. Expansion is accomplished easily in both word width and word depth.

The SN74ACT7881 has normal input-bus to output-bus asynchronous operation. The special enable circuitry adds the ability to synchronize independent reads and writes to their respective system clocks.

The SN74ACT7881 is characterized for operation from 0°C to 70°C.



logic symbol†

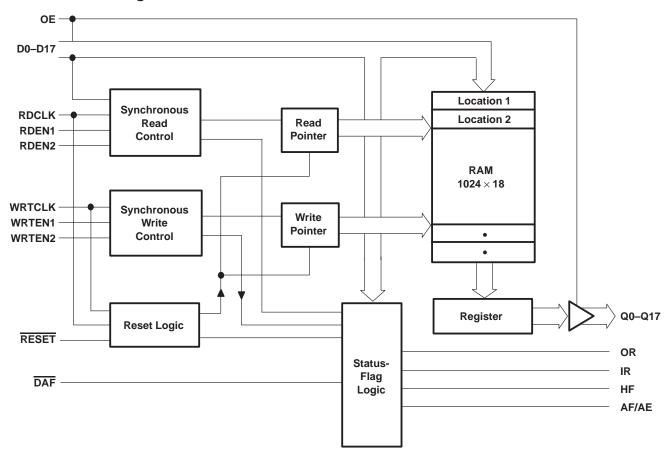


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the FN package.



CLOCKED FIRST-IN, FIRST-OUT MEMORY SCAS227E – FEBRUARY 1993 – REVISED APRIL 1998

functional block diagram





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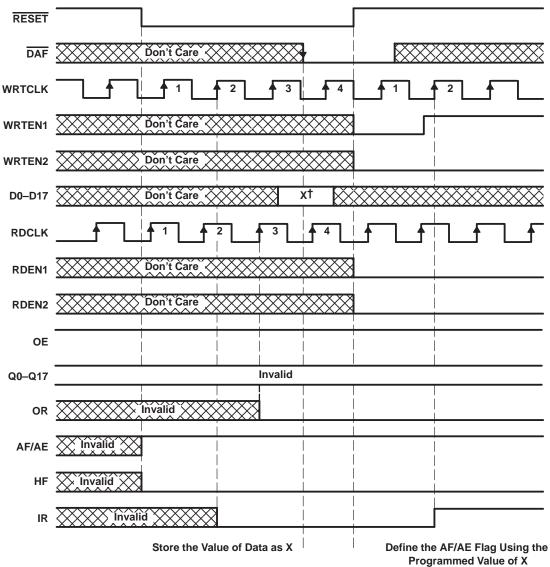
Terminal Functions

TERMINAL†			DECORPTION					
NAME	NO.	I/O	DESCRIPTION					
AF/AE	33	0	Almost-full/almost-empty flag. The AF/AE boundary is defined by the AF/AE offset value (X). This value can be programmed during reset, or the default value of 256 can be used. AF/AE is high when the FIFO contains (X + 1) or fewer words or $(1025 - X)$ or more words. AF/AE is low when the FIFO contains between (X + 2) and $(1024 - X)$ words. Programming procedure for AF/AE – The AF/AE flag is programmed during each reset cycle. The AF/AE offset value (X) is either a user-defined value or the default of X = 256. Instructions to program AF/AE using both methods are as follows:					
			User-defined X Step 1: Take DAF from high to low. Step 2: If RESET is not already low, take RESET low. Step 3: With DAF held low, take RESET high. This defines the AF/AE using X. Step 4: To retain the current offset for the next reset, keep DAF low. Default X					
			To redefine AF/AE using the default value of X = 256, hold DAF high during the reset cycle.					
DAF	27	ı	Define-almost-full. The high-to-low transition of DAF stores the binary value of data inputs as the AF/AE offset value (X). With DAF held low, a low pulse on RESET defines the AF/AE flag using X.					
D0-D17	26–19, 17, 15–7	I	Data inputs for 18-bit-wide data to be stored in the memory. A high-to-low transition of \overline{DAF} captures data for the AF/AE offset (X) from D8–D0.					
HF	36	0	Half-full flag. HF is high when the FIFO contains 512 or more words and is low when the number of words in memory is less than half the depth of the FIFO.					
IR	35	0	Input-ready flag. IR is high when the FIFO is not full and low when the device is full. During reset, IR is driven low on the rising edge of the second WRTCLK pulse. IR is then driven high on the rising edge of the second WRTCLK pulse after RESET goes high. After the FIFO is filled and IR is driven low, IR is driven high on the second WRTCLK pulse after the first valid read.					
OE	2	I	Output enable. The Q0–Q17 outputs are in the high-impedance state when OE is low. OE must be high before the rising edge of RDCLK to read a word from memory.					
OR	66	0	Output-ready flag. OR is high when the FIFO is not empty and low when the FIFO is empty. During reset, OR is set low on the rising edge of the third RDCLK pulse. OR is set high on the rising edge of the third RDCLK pulse to occur after the first word is written into the FIFO. OR is set low on the rising edge of the first RDCLK pulse after the last word is read.					
Q0-Q17	38–39, 41–42, 44, 46–47, 49–50, 52–53, 55–56, 58–59, 61, 63–64	0	Data outputs. The first data word to be loaded into the FIFO is moved to Q0–Q17 on the rising edge of the third RDCLK pulse to occur after the first valid write. RDEN1 and RDEN2 do not affect this operation. Following data is unloaded on the rising edge of RDCLK when RDEN1, RDEN2, OE, and OR are high.					
RDCLK	5	I	Read clock. Data is read out of memory on the low-to-high transition of RDCLK if OR, OE, RDEN1, and RDEN2 are high. RDCLK is a free-running clock and functions as the synchronizing clock for all data transfers out of the FIFO. OR also is driven synchronously with respect to the RDCLK signal.					
RDEN1 RDEN2	4 3	1	Read enable. RDEN1 and RDEN2 must be high before a rising edge on RDCLK to read a word out of memory. RDEN1 and RDEN2 are not used to read the first word stored in memory.					
RESET	1	I	Reset. A reset is accomplished by taking RESET low and generating a minimum of four RDCLK and WRTCLK cycles. This ensures that the internal read and write pointers are reset and that OR, HF, and IR are low, and AF/AE is high. The FIFO must be reset upon power up. With DAF at a low level, a low pulse on RESET defines AF/AE using the AF/AE offset value (X), where X is the value previously stored. With DAF at a high level, a low-level pulse on RESET defines the AF/AE flag using the default value of X = 256.					
WRTCLK	29	I	Write clock. Data is written into memory on a low-to-high transition of WRTCLK if IR, WRTEN1, and WRTEN2 are high. WRTCLK is a free-running clock and functions as the synchronizing clock for all data transfers into the FIFO. IR also is driven synchronously with respect to WRTCLK.					
WRTEN1 WRTEN2	30 31	I	Write enable. WRTEN1 and WRTEN2 must be high before a rising edge on WRTCLK for a word to be written into memory. WRTEN1 and WRTEN2 do not affect the storage of the AF/AE offset value (X).					

[†] Terminals listed are for the FN package.



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[†] X is the binary value on D8–D0.

Figure 1. Reset Cycle: Define AF/AE Flag Using a Programmed Value of X



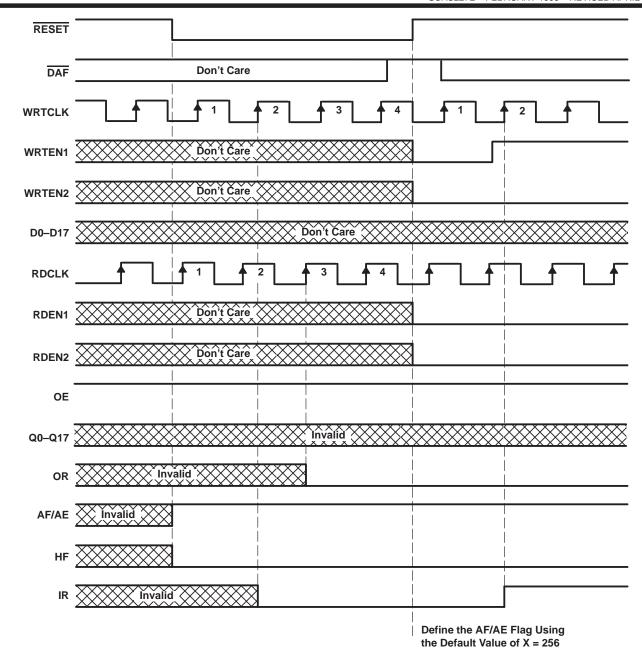
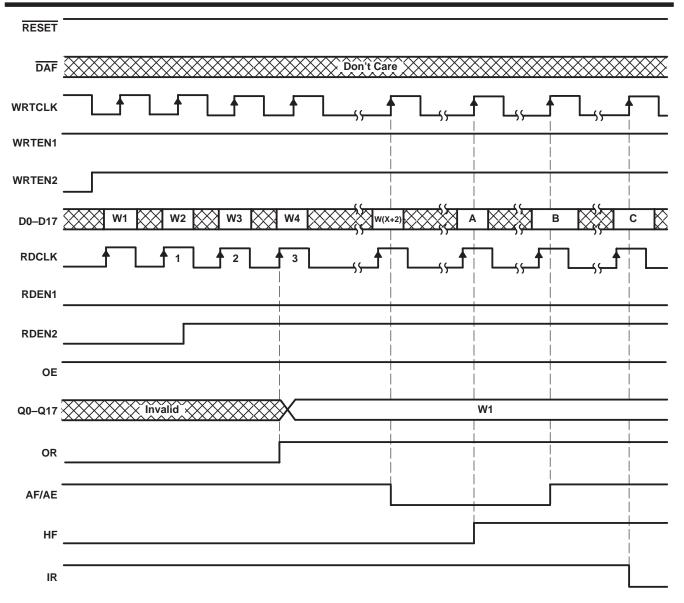


Figure 2. Reset Cycle: Define AF/AE Flag Using the Default Value of X = 256

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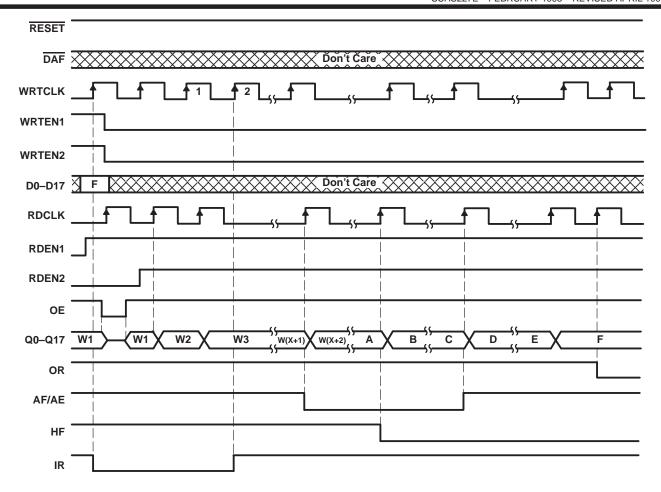


DATA-WORD NUMBERS FOR FLAG TRANSITIONS

TRANSITION WORD							
Α	В	С					
W513	W(1025 – X)	W1025					

Figure 3. Write Cycle





DATA-WORD NUMBERS FOR FLAG TRANSITIONS

TRANSITION WORD										
Α	В	С	D	E	F					
W513	W514	W(1024 – X)	W(1025 – X)	W1024	W1025					

Figure 4. Read Cycle

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absolute maximum ratings over operating free-air temperature range†

Supply voltage range, V _{CC}	0.5 V to 7 \
Input voltage range, V _I	0.5 V to 7 \
Voltage range applied to a disabled 3-state output	
Package thermal impedance, θ_{JA} (see Note 1): FN package	39°C/W
PN package	62°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions

		MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		V
V _{IL}	Low-level input voltage		0.8	V
ІОН	High-level output current		-8	mA
loL	Low-level output current		16	mA
TA	Operating free-air temperature	0	70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	Т	MIN	TYP [‡]	MAX	UNIT	
Voн	$V_{CC} = 4.5 V,$	$I_{OH} = -8 \text{ mA}$	2.4			V
VoL	$V_{CC} = 4.5 V,$	$I_{OL} = 16 \text{ mA}$			0.5	V
lį	V _{CC} = 5.5 V,	VI = VCC or 0			±5	μΑ
loz	$V_{CC} = 5.5 V$,	$V_O = V_{CC}$ or 0			±5	μΑ
. 8	$V_{I} = V_{CC} - 0.2 \text{ V or } 0$				400	μΑ
I _{CC} §	One input at 3.4 V,	Other inputs at V _{CC} or GND			1.2	mA
Ci	V _I = 0,	f = 1 MHz		4		pF
Co	$V_{O} = 0,$	f = 1 MHz		8		pF

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[§] I_{CC} is tested with outputs open.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (see Figures 1 through 5)

			'ACT78	881-15	5 'ACT7881-20		'ACT78	81-30	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	UNII
fclock	Clock frequency			67		50		33.4	MHz
		WRTCLK high	5		7		8.5		
		WRTCLK low	7		7		11		
t _W	Pulse duration	RDCLK high	5		7		8.5		ns
		RDCLK low	7		7		11		
		DAF high	7		7		10		
		D0–D17 before WRTCLK↑	5		5		5		
		WRTEN1, WRTEN2 high before WRTCLK↑	4		5		5		
	fclock Clock frequency 67 50 33 t _W Pulse duration 5 7 8.5 WRTCLK low 7 7 11 RDCLK high 5 7 8.5 RDCLK low 7 7 11 DAF high 7 7 10 D0-D17 before WRTCLK↑ 5 5 5	OE, RDEN1, RDEN2 high before RDCLK↑	4		5		5		
t _{su}			5		6		7		ns
		Define AF/AE: D0–D8 before DAF↓	3		5		5		
		Define AF/AE: DAF↓ before RESET↑	3		6		7		
		D0–D17 after WRTCLK↑	0		0		0		
		WRTEN1, WRTEN2 high after WRTCLK↑	0		0		0		
		OE, RDEN1, RDEN2 high after RDCLK↑	0		0		0		
t _h	Hold time		0		0		0		ns
		Define AF/AE: D0–D8 after DAF↓	0		0		0		
		Define AF/AE: DAF low after RESET↑			0		0		
		Define AF/AE (default): DAF high after RESET↑	0		0		0		

[†] To permit the clock pulse to be utilized for reset purposes

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 5)

PARAMETER	FROM	ТО	'ACT78	'ACT7881-15		381-20	'ACT78		
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
f _{max}	WRTCLK or RDCLK		67		50		33.4		MHz
^t pd	RDCLK↑	Any Q	3	12	3	13	3	18	ns
t _{pd} ‡	RDCLK↑	Any Q							ns
	WRTCLK↑	IR	2	8	2	9.5	2	12	
.	RDCLK↑	OR	2	8	2	9.5	2	12	20
^t pd	WRTCLK↑	AF/AE	6	17	6	19	6	22	ns
	RDCLK↑	AF/AE	6	17	6	19	6	22	
^t PLH	WRTCLK↑	HF	6	14	6	17	6	21	ns
^t PHL	RDCLK↑	HF	6	14	6	17	6	21	ns
^t PLH	RESET↓	AF/AE	3	12	3	17	3	21	ns
^t PHL	RESET↓	HF	3	14	3	19	3	23	ns
t _{en}	OE	Any Q	2	9	2	11	2	11	ns
^t dis	OE	Any Q	2	10	2	14	2	14	ns

[‡] This parameter is measured with $C_L = 30 pF$ (see Figure 6).



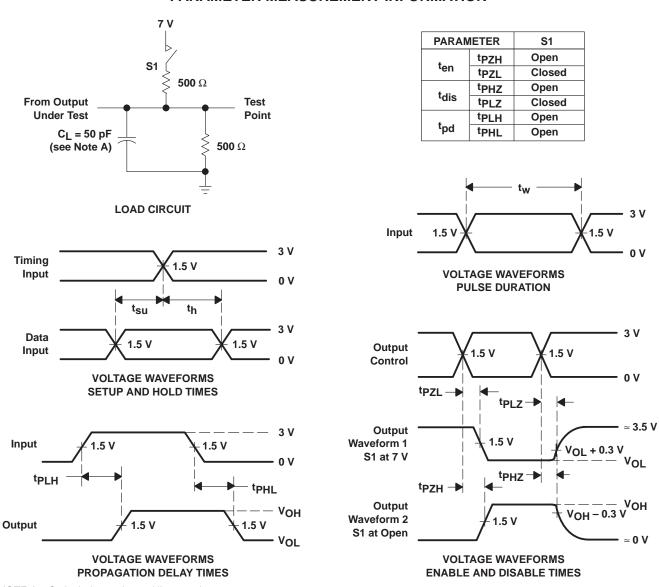
CLOCKED FIRST-IN, FIRST-OUT MEMORY

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operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	TYP	UNIT	
C _{pd}	Power dissipation capacitance per 1K bits	$C_L = 50 pF$,	f = 5 MHz	65	pF

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes probe and jig capacitance.

Figure 5. Load Circuit and Voltage Waveforms



TYPICAL CHARACTERISTICS

PROPAGATION DELAY TIME

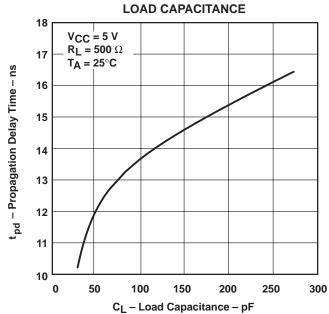


Figure 6

APPLICATION INFORMATION

expanding the SN74ACT7881

The SN74ACT7881 is expandable in both word width and word depth. Word-depth expansion is accomplished by connecting the devices in series such that data flows through each device in the chain. Figure 8 shows two SN74ACT7881 devices configured for word-depth expansion. The common clock between the devices can be tied to either the write clock (WRTCLK) of the first device or the read clock (RDCLK) of the last device. The output-ready (OR) flag of the previous device and the input-ready (IR) flag of the next device maintain data flow to the last device in the chain whenever space is available.

Figure 9 shows two SN74ACT7881 devices in word-width expansion. Word-width expansion is accomplished by simply connecting all common control signals between the devices and creating composite IR and OR signals. The almost-full/almost-empty (AF/AE) flag and half-full (HF) flag can be sampled from any one device. Word-depth expansion and word-width expansion can be used together.

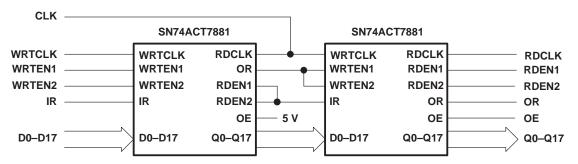


Figure 7. Word-Depth Expansion: $2048/4096/8192 \times 18$ Bits, N = 2

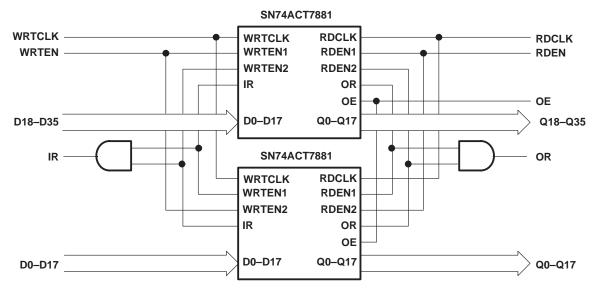


Figure 8. Word-Width Expansion: 1024 × 36 Bits





PACKAGE OPTION ADDENDUM

9-Sep-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74ACT7881-20PN	LIFEBUY	LQFP	PN	80		TBD	Call TI	Call TI	0 to 70	ACT7881-20	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

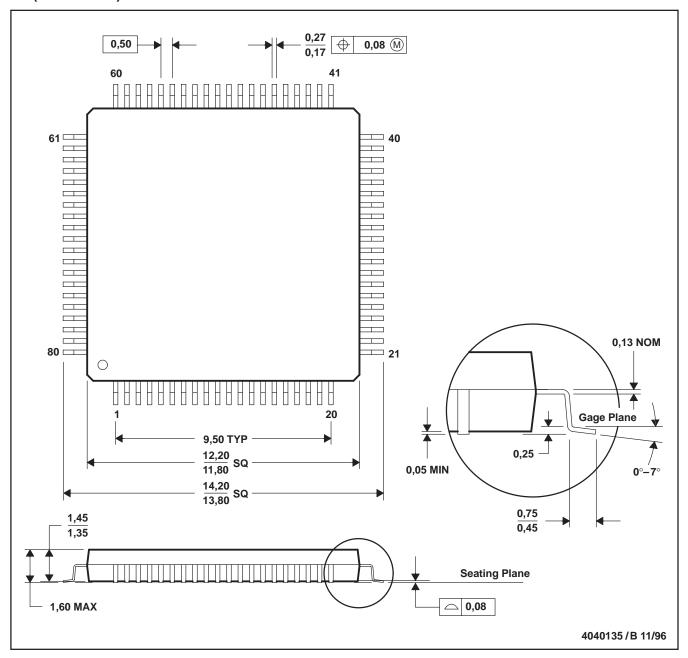
- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PN (S-PQFP-G80)

PLASTIC QUAD FLATPACK



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-026

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